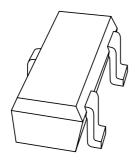
### DISCRETE SEMICONDUCTORS

# DATA SHEET



# **2PB709A**PNP general purpose transistor

Product data sheet Supersedes data of 1997 Jun 19 1999 Apr 23



NXP Semiconductors Product data sheet

## PNP general purpose transistor

2PB709A

#### **FEATURES**

• Low current (max. 100 mA)

• Low voltage (max. 45 V).

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

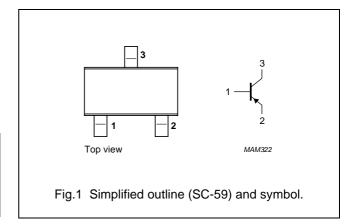
PNP transistor in an SC-59 plastic package. NPN complement: 2PB601A.

#### **MARKING**

| TYPE NUMBER | MARKING CODE |
|-------------|--------------|
| 2PB709AQ    | BQ           |
| 2PB709AR    | BR           |
| 2PB709AS    | BS           |

#### **PINNING**

| PIN | DESCRIPTION |
|-----|-------------|
| 1   | base        |
| 2   | emitter     |
| 3   | collector   |



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL           | PARAMETER                     | CONDITIONS                       | MIN. | MAX.       | UNIT |
|------------------|-------------------------------|----------------------------------|------|------------|------|
| V <sub>CBO</sub> | collector-base voltage        | open emitter                     | _    | -45        | V    |
| V <sub>CEO</sub> | collector-emitter voltage     | open base                        | _    | <b>-45</b> | V    |
| V <sub>EBO</sub> | emitter-base voltage          | open collector                   | _    | -6         | V    |
| I <sub>C</sub>   | collector current (DC)        |                                  | _    | -100       | mA   |
| I <sub>CM</sub>  | peak collector current        |                                  | _    | -200       | mA   |
| I <sub>BM</sub>  | peak base current             |                                  | _    | -100       | mA   |
| P <sub>tot</sub> | total power dissipation       | T <sub>amb</sub> ≤ 25 °C; note 1 | _    | 250        | mW   |
| T <sub>stg</sub> | storage temperature           |                                  | -65  | +150       | °C   |
| T <sub>j</sub>   | junction temperature          |                                  | _    | 150        | °C   |
| T <sub>amb</sub> | operating ambient temperature |                                  | -65  | +150       | °C   |

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

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# PNP general purpose transistor

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#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                                   | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R <sub>th j-a</sub> | thermal resistance from junction to ambient | note 1     | 500   | K/W  |

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

| SYMBOL             | PARAMETER                            | CONDITIONS   | MIN. | MAX.       | UNIT |
|--------------------|--------------------------------------|--|------|------------|------|
| I <sub>CBO</sub>   | collector cut-off current            | I <sub>E</sub> = 0; V <sub>CB</sub> = -45 V                          | _    | -10        | nA   |
|                    |                                      | I <sub>E</sub> = 0; V <sub>CB</sub> = -45 V; T <sub>j</sub> = 150 °C | _    | <b>-</b> 5 | μΑ   |
| I <sub>EBO</sub>   | emitter cut-off current              | $I_C = 0; V_{EB} = -5 \text{ V}$                                     | _    | -10        | nA   |
| h <sub>FE</sub>    | DC current gain                      | $I_C = -2 \text{ mA}; V_{CE} = -10 \text{ V}$                        |      |            |      |
|                    | 2PB709AQ                             |  | 160  | 260        |      |
|                    | 2PB709AR                             |  | 210  | 340        |      |
|                    | 2PB709AS                             |  | 290  | 460        |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | $I_C = -100 \text{ mA}$ ; $I_B = -10 \text{ mA}$ ; note 1            | _    | -500       | mV   |
| C <sub>c</sub>     | collector capacitance                | $I_E = i_e = 0$ ; $V_{CB} = -10 \text{ V}$ ; $f = 1 \text{ MHz}$     | _    | 5          | pF   |
| f <sub>T</sub>     | transition frequency                 | $I_C = -1 \text{ mA}; V_{CE} = -10 \text{ V}; f = 100 \text{ MHz}$   |      |            |      |
|                    | 2PB709AQ                             |  | 60   | _          | MHz  |
|                    | 2PB709AR                             |  | 70   | _          | MHz  |
|                    | 2PB709AS                             |  | 80   | _          | MHz  |

#### Note

1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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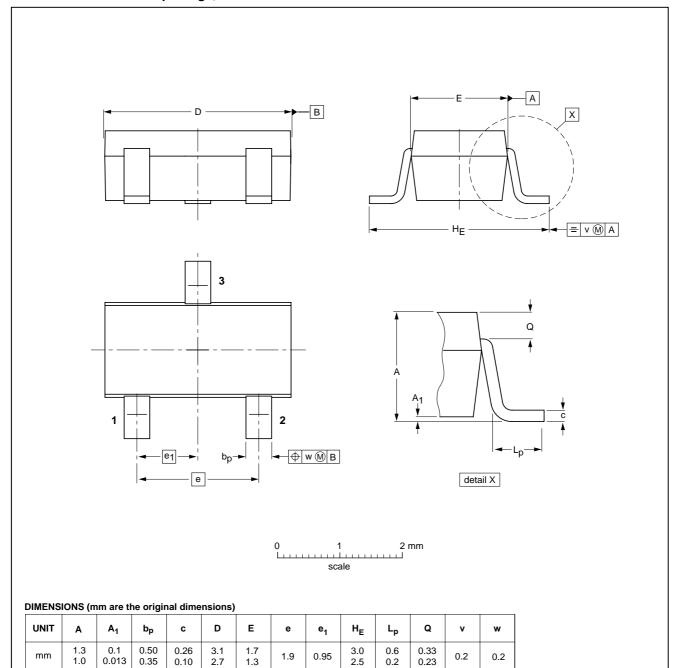
# PNP general purpose transistor

2PB709A

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

**SOT346** 



| OUTLINE | REFERENCES |        | EUROPEAN | ISSUE DATE |            |            |
|---------|------------|--------|----------|------------|------------|------------|
| VERSION | IEC        | JEDEC  | EIAJ     |            | PROJECTION | ISSUE DATE |
| SOT346  |            | TO-236 | SC-59    |            |            | 98-07-17   |

0.95

0.6

0.33

0.23

0.2

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0.50

0.35

mm

0.26

0.10

3.1 2.7

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#### PNP general purpose transistor

2PB709A

#### **DATA SHEET STATUS**

| DOCUMENT<br>STATUS <sup>(1)</sup> | PRODUCT<br>STATUS <sup>(2)</sup> | DEFINITION  |
|-----------------------------------|----------------------------------|---|
| Objective data sheet              | Development                      | This document contains data from the objective specification for product development. |
| Preliminary data sheet            | Qualification                    | This document contains data from the preliminary specification.                       |
| Product data sheet                | Production                       | This document contains the product specification.                                     |

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#### **Contact information**

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